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# Vishay Semiconductors

# Infrared Transceiver Module (SIR, 115.2 kbit/s) for IrDA® Applications





20110-1

#### **DESCRIPTION**

TFDU4101 is an infrared transceiver that supports data rates up to 115 kbit/s per the IrDA standard. The link distance is up to 1 meter. The transceiver includes a PIN photodiode, an infrared emitter, and a low-power control IC. These components have not been qualified according to automotive specifications.

#### **FEATURES**

- Compliant to the IrDA physical layer specification
- Standard IrDA link distance of 1 m
- Low power consumption, typically less than 70 μA
- Less than 1 μA in shutdown mode
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

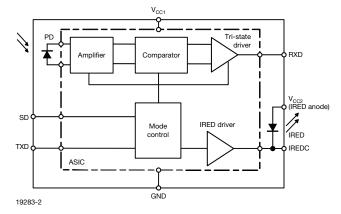
### **APPLICATIONS**

- · Short-distance wireless communication and data transfer
- Use in environments where RF is problematic

#### **DESIGN SUPPORT TOOLS**

- 3D model
- Window size calculator
- Symbols and terminology
- IRDC protocol
- Reference layouts and circuit diagrams

#### **FUNCTIONAL BLOCK DIAGRAM**



#### **LINKS TO ADDITIONAL RESOURCES**









| PRODUCT SUMM | IARY                  |   |                      |                             |                                |
|--------------|-----------------------|---|----------------------|-----------------------------|--------------------------------|
| PART NUMBER  | DATA RATE<br>(kbit/s) | DIMENSIONS<br>H x L x W<br>(mm x mm x mm) | LINK DISTANCE<br>(m) | OPERATING<br>VOLTAGE<br>(V) | IDLE SUPPLY<br>CURRENT<br>(mA) |
| TFDU4101     | 115.2                 | 4 x 9.7 x 4.7                             | 0 to ≥ 1             | 2.4 to 5.5                  | 0.07                           |

| PARTS TABLE  |   |          |
|--------------|---|----------|
| PART         | DESCRIPTION   | QTY/REEL |
| TFDU4101-TR3 | Oriented in carrier tape for side view surface mounting | 1000 pcs |
| TFDU4101-TT3 | Oriented in carrier tape for top view surface mounting  | 1000 pcs |

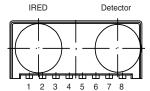
| PIN DESC      | RIPTION                        |  |     |        |
|---------------|--------------------------------|--|-----|--------|
| PIN<br>NUMBER | SYMBOL                         | DESCRIPTION  | I/O | ACTIVE |
| 1             | V <sub>CC2</sub><br>IRED anode | IRED anode to be externally connected to $V_{CC2}$ . An external resistor is only necessary for controlling the IRED current when a current reduction below 300 mA is intended to operate in IrDA low power mode. This pin is allowed to be supplied from an uncontrolled power supply separated from the controlled $V_{CC1}$ - supply. |     |        |
| 2             | IRED cathode                   | IRED cathode, internally connected to driver transistor  |     |        |
| 3             | TXD                            | This Schmitt-Trigger input is used to transmit serial data when SD is low. An on-chip protection circuit disables the LED driver if the TXD pin is asserted for longer than 50 µs (max. 300 µs).   | I   | High   |
| 4             | RXD                            | Received data output, push-pull CMOS driver output capable of driving standard CMOS or TTL loads. During transmission the RXD output is active (echo-on). No external pull-up or pull-down resistor is required. Floating with a weak pull-up of 500 k $\Omega$ (typ.) in shutdown mode.   | 0   | Low    |
| 5             | SD                             | Shutdown   | 1   | High   |
| 6             | V <sub>CC1</sub>               | Supply voltage   |     |        |
| 7             | NC                             | No internal connection   | l l |        |
| 8             | GND                            | Ground   |     |        |



### TFDU4101 Weight 200 mg

**PINOUT** 

"U" Option Baby Face (universal)



17087

| ABSOLUTE MAXIMUM RATI                           | NGS   |                        |      | 1    |                 |      |
|---|---|------------------------|------|------|-----------------|------|
| PARAMETER                                       | TEST CONDITIONS                               | SYMBOL                 | MIN. | TYP. | MAX.            | UNIT |
| Supply voltage range, transceiver               | -0.3 V < V <sub>CC2</sub> < 6 V               | V <sub>CC1</sub>       | -0.5 | -    | 6               | V    |
| Supply voltage range, transmitter               | -0.5 V < V <sub>CC1</sub> < 6 V               | $V_{CC2}$              | -0.5 | -    | 6               | V    |
| Voltage at RXD                                  | -0.5 V < V <sub>CC1</sub> < 6 V               | $V_{RXD}$              | -0.5 | -    | $V_{CC1} + 0.5$ | V    |
| Voltage at all inputs and outputs               | V <sub>in</sub> > V <sub>CC1</sub> is allowed | V <sub>in</sub>        | -0.5 | -    | 6               | V    |
| Input currents                                  | For all pins, except IRED anode pin           |                        | =    | -    | 10              | mA   |
| Output sinking current                          |   |                        | -    | -    | 25              | mA   |
| Power dissipation                               |   | $P_D$                  | =    | -    | 250             | mW   |
| Junction temperature                            |   | TJ                     | -    | -    | 125             | °C   |
| Ambient temperature range (operating)           |   | T <sub>amb</sub>       | -30  | -    | +85             | °C   |
| Storage temperature range                       |   | T <sub>stg</sub>       | -30  | -    | +85             | °C   |
| Soldering temperature                           | See "Recommended Solder Profile"              |                        | =    | -    | 260             | °C   |
| Average output current, pin 1                   |   | I <sub>IRED</sub> (DC) | -    | -    | 80              | mA   |
| Repetitive pulse output current, pin 1 to pin 2 | < 90 μs, t <sub>on</sub> < 20 %               | I <sub>IRED</sub> (RP) | -    | -    | 400             | mA   |
| Thermal resistance junction-to-ambient          | JESD51  | R <sub>thJA</sub>      | -    | 300  | -               | K/W  |

#### Note

 Reference point pin, GND unless otherwise noted. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

| EYE SAFETY INFORMATION  |                |
|---|----------------|
| STANDARD  | CLASSIFICATION |
| IEC/EN 60825-1 (2007-03), DIN EN 60825-1 (2008-05) "SAFETY OF LASER PRODUCTS - Part 1: equipment classification and requirements", simplified method  | Class 1        |
| IEC 62471 (2006), CIE S009 (2002) "Photobiological Safety of Lamps and Lamp Systems"  | Exempt         |
| DIRECTIVE 2006/25/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 5 <sup>th</sup> April 2006 on the minimum health and safety requirements regarding the exposure of workers to risks arising from physical agents (artificial optical radiation) (19 <sup>th</sup> individual directive within the meaning of article 16(1) of directive 89/391/EEC) | Exempt         |

#### Note

· Vishay transceivers operating inside the absolute maximum ratings are classified as eye safe according the above table



| PARAMETER  | TEST CONDITIONS/PINS   | SYMBOL            | MIN.                   | TYP. | MAX.                    | UNIT     |
|--|--|-------------------|------------------------|------|-------------------------|----------|
| TRANSCEIVER  |  |                   |                        |      |                         |          |
| Supply voltage   |  | V <sub>CC1</sub>  | 2.4                    | -    | 5.5                     | V        |
| Dynamic supply current   | $SD = low, E_e = 1 klx (1), \\ T_{amb} = -25 °C to +85 °C \\ V_{CC1} = V_{CC2} = 2.4 V to 5.5 V$ | I <sub>CC1</sub>  | 40                     | 90   | 130                     | μΑ       |
| Dynamic supply current   | $SD = low, E_e = 1 klx (1),  T_{amb} = 25 °C  V_{CC1} = V_{CC2} = 2.4 V to 5.5 V$                | I <sub>CC1</sub>  | 40                     | 75   | -                       | μΑ       |
| Average dynamic supply current, transmitting                                       | I <sub>IRED</sub> = 300 mA,<br>25 % duty cycle   | Icc               | -                      | 0.65 | 2.5                     | mA       |
|  | SD = high, T = 25 °C, E <sub>e</sub> = 0 klx<br>no signal, no resistive load                     | I <sub>SD</sub>   | -                      | 0.01 | 0.1                     | μΑ       |
| Shutdown supply current  | SD = high, T = 70 °C<br>no signal, no resistive load   | I <sub>SD</sub>   | -                      | -    | 1                       | μΑ       |
|  | SD = high, T = 85 °C<br>no signal, no resistive load   | I <sub>SD</sub>   | -                      | -    | 1                       | μΑ       |
| Operating temperature range  |  | T <sub>A</sub>    | -30                    | -    | +85                     | °C       |
| Output voltage low, RXD  | C <sub>load</sub> = 15 pF  | V <sub>OL</sub>   | -0.5                   | -    | 0.15 x V <sub>CC1</sub> | V        |
| Output voltage high, RXD   | $I_{OH} = -500 \mu A, C_{Load} = 15 pF$  | V <sub>OH</sub>   | 0.8 x V <sub>CC1</sub> | -    | V <sub>CC1</sub> + 0.5  | V        |
| Output voltage high, HAD   | $I_{OH} = -250 \mu A, C_{Load} = 15 pF$  | $V_{OH}$          | 0.9 x V <sub>CC1</sub> | -    | V <sub>CC1</sub> + 0.5  | V        |
| RXD to V <sub>CC1</sub> impedance  |  | R <sub>RXD</sub>  | 400                    | 500  | 600                     | kΩ       |
| Input voltage low (TXD, SD)  | SD = high  | $V_{IL}$          | -0.5                   | -    | 0.5                     | V        |
| Input voltage high (TXD, SD)   |  | V <sub>IH</sub>   | V <sub>CC1</sub> - 0.5 | -    | 6                       | V        |
| Input leakage current (TXD, SD)  | V <sub>in</sub> = 0.9 x V <sub>CC1</sub>   | I <sub>ICH</sub>  | -2                     | -    | +2                      | μΑ       |
| Controlled pull down current $0 < V_{in} < 0.15 V_{CC1}$<br>$V_{in} > 0.7 V_{CC1}$ | SD, TXD = "0" or "1"   | I <sub>IrTX</sub> | -1                     | 0    | +150<br>1               | μΑ<br>μΑ |
| Input capacitance (TXD, SD)  |  | Cl                | -                      | -    | 5                       | pF       |

#### Notes

<sup>•</sup> Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

<sup>(1)</sup> Standard illuminant A

<sup>(2)</sup> The typical threshold level is 0.5 x V<sub>CC1</sub>. It is recommended to use the specified min./max. values to avoid increased operating current



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| PARAMETER  | TEST CONDITIONS   | SYMBOL                                | MIN.                    | TYP.      | MAX.                       | UNIT                                       |
|--|---|---------------------------------------|-------------------------|-----------|----------------------------|--|
| RECEIVER   |   |                                       |                         |           |                            |  |
| Minimum irradiance E <sub>e</sub> in angular range <sup>(2)</sup> SIR mode | 9.6 kbit/s to 115.2 kbit/s $\lambda$ = 850 nm to 900 nm; $\alpha$ = 0°, 15°   | E <sub>e, min.</sub>                  | 4<br>(0.4)              | 20<br>(2) | 35 <sup>(1)</sup><br>(3.5) | mW/m <sup>2</sup><br>(μW/cm <sup>2</sup> ) |
| Maximum irradiance E <sub>e</sub> in angular range <sup>(3)</sup>          | λ = 850 nm to 900 nm  | E <sub>e, max</sub> .                 | 5<br>(500)              | -         | -                          | kW/m <sup>2</sup><br>(mW/cm <sup>2</sup> ) |
| Rise time of output signal   | 10 % to 90 %, C <sub>L</sub> = 15 pF  | t <sub>r (RXD)</sub>                  | 20                      | -         | 100                        | ns   |
| Fall time of output signal   | 90 % to 10 %, C <sub>L</sub> = 15 pF  | t <sub>f (RXD)</sub>                  | 20                      | -         | 100                        | ns   |
| RXD pulse width  | Input pulse length > 1.2 μs   | t <sub>PW</sub>                       | 1.65                    | 2.2       | 3                          | μs   |
| Leading edge jitter  | Input irradiance = 100 mW/m²,<br>≤ 115.2 kbit/s   |                                       | -                       | -         | 250                        | ns   |
| Standby/shutdown delay, receiver startup time                              | After shutdown active or power-on   |                                       | -                       | 100       | 500                        | μs   |
| Latency  |   | t∟                                    | -                       | 100       | 150                        | μs   |
| TRANSMITTER (new surface e   | emitter values introduced via PCN OPT-1210  | -2022)                                |                         |           |                            |  |
| IRED operating current limitation  | No external resistor for current limitation (4)   | I <sub>D</sub>                        | 200                     | 300       | 430                        | mA   |
| Forward voltage of built-in IRED   | I <sub>f</sub> = 300 mA   | V <sub>f</sub>                        | 1.4                     | 1.8       | 1.9                        | V  |
| Output leakage IRED current  | TXD = 0 V, 0 < V <sub>CC1</sub> < 5.5 V   | I <sub>IRED</sub>                     | -1                      | 0.01      | 1                          | μΑ   |
|  | $\alpha$ = 0°, 15°, TXD = high, SD = low  | l <sub>e</sub>                        | 50                      | 150       | 400                        | mW/sr                                      |
| Output radiant intensity   | $V_{CC1} = 5 \text{ V}, \alpha = 0^{\circ}, 15^{\circ}, \\ TXD = \text{low or SD} = \text{high} \\ \text{(receiver is inactive as long as SD} = \text{high)}$ | l <sub>e</sub>                        | -                       | -         | 0.04                       | mW/sr                                      |
| Output radiant intensity, angle of half intensity                          |   | α                                     | -                       | ± 30      | -                          | 0  |
| Peak - emission wavelength (5)   |   | $\lambda_{p}$                         | 870                     | =         | 910                        | nm   |
| Spectral bandwidth   |   | Δλ                                    | -                       | 45        | -                          | nm   |
| Optical rise time, fall time   |   | t <sub>ropt</sub> , t <sub>fopt</sub> | 10                      | 50        | 100                        | ns   |
| Optical output pulse duration  | Input pulse width 1.6 $< t_{TXD} < 23 \mu s$  | t <sub>opt</sub>                      | t <sub>TXD</sub> - 0.15 |           | t <sub>TXD</sub> + 0.15    | μs   |
| Optical output pulse duration  | Input pulse width $t_{TXD} \ge 23 \ \mu s$  | t <sub>opt</sub>                      | 23                      | 50        | 100                        | μs   |
| Optical overshoot  |   |                                       |                         |           | 25                         | %  |

#### Notes

- · Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- (1) IrDA specification is 40 mW/m². Specification takes a window loss of 10 % into account
- (2) IrDA sensitivity definition: minimum irradiance E<sub>e</sub> in angular range, power per unit area. The receiver must meet the BER specification while the source is operating at the minimum intensity in angular range into the minimum half-angular range at the maximum link length
- (3) Maximum irradiance E<sub>e</sub> in angular range, power per unit area. The optical delivered to the detector by a source operating at the maximum intensity in angular range at minimum link length must not cause receiver overdrive distortion and possible ralated link errors. If placed at the active output interface reference plane of the transmitter, the receiver must meet its bit error ratio (BER) specification
- (4) Using an external current limiting resistor is allowed and recommended to reduce IRED intensity and operating current when current reduction is intended to operate at the IrDA low power conditions. E.g. for  $V_{CC2} = 3.3$  V a current limiting resistor of  $R_S = 56 \Omega$  will allow a power minimized operation at IrDA low power conditions
- (5) Due to this wavelength restriction compared to the IrDA spec of 850 nm to 900 nm the transmitter is able to operate as source for the standard remote control applications with codes as e.g. Phillips RC5/RC6® or RECS 80

For more definitions see the document "Symbols and Terminology" on the Vishay website.

#### RECOMMENDED CIRCUIT DIAGRAM

Operated with a clean low impedance power supply the TFDU4101 needs no additional external components. However, depending on the entire system design and board layout, additional components may be required (see figure 1). That is especially the case when separate power supplies are used for bench tests. When using compact wiring and regulated supplies as e. g. in phone applications in most cases no external components are necessary.

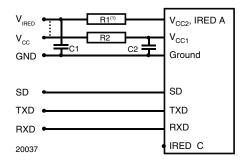


Fig. 1 - Recommended Test Circuit

#### Note

(1) R1 is optional when reduced intensity is used

The capacitor C1 is buffering the supply voltage and eliminates the inductance of the power supply line. This one should be a Tantalum or other fast capacitor to guarantee the fast rise time of the IRED current. The resistor R1 is the current limiting resistor, which may be used to reduce the operating current to levels below the specified controlled values for saving battery power.

Vishay's transceivers integrate a sensitive receiver and a built-in power driver. The combination of both needs a careful circuit board layout. The use of thin, long, resistive and inductive wiring should be avoided. The shutdown input must be grounded for normal operation, also when the shutdown function is not used.

The inputs (TXD, SD) and the output RXD should be directly connected (DC-coupled) to the I/O circuit. The capacitor C2 combined with the resistor R2 is the low pass filter for smoothing the supply voltage. R2, C1 and C2 are optional and dependent on the quality of the supply voltages  $V_{\rm CC1}$  and injected noise. An unstable power supply with dropping voltage during transmission may reduce the sensitivity (and transmission range) of the transceiver.

The placement of these parts is critical. It is strongly recommended to position C2 as close as possible to the transceiver power supply pins.

When extended wiring is used (bench tests!) the inductance of the power supply can cause dynamically a voltage drop at  $V_{CC2}$ . Often some power supplies are not able to follow the fast current rise time. In that case another 4.7  $\mu$ F (type, see table under C1) at  $V_{CC2}$  will be helpful.

Under extreme EMI conditions as placing an RF-transmitter antenna on top of the transceiver, we recommend to protect all inputs by a low-pass filter, as a minimum a 12 pF capacitor, especially at the RXD port. The transceiver itself withstands EMI at GSM frequencies above 500 V/m. When interference is observed, the wiring to the inputs picks it up. It is verified by DPI measurements that as long as the interfering RF - voltage is below the logic threshold levels of the inputs and equivalent levels at the outputs no interferences are expected.

One should keep in mind that basic RF-design rules for circuit design should be taken into account. Especially longer signal lines should not be used without termination. See e.g. "The Art of Electronics" Paul Horowitz, Winfield Hill, 1989, Cambridge University Press, ISBN: 0521370957.

| TABLE 1 - RI | TABLE 1 - RECOMMENDED TESTS AND APPLICATION CIRCUIT COMPONENTS |  |  |  |  |
|--------------|--|--|--|--|--|
| COMPONENT    | RECOMMENDED VALUE  | VISHAY PART NUMBER   |  |  |  |
| C1           | 4.7 μF, 16 V   | 293D 475X9 016B  |  |  |  |
| C2           | 0.1 μF, ceramic  | VJ 1206 Y 104 J XXMT   |  |  |  |
| R1           | Depends on current to be adjusted, e. g. with $V_{CC2} = 3$ .  | 3 V 56 $\Omega$ is an option for minimum low power operation |  |  |  |
| R2           | 47 Ω, 0.125 W  | CRCW-1206-47R0-F-RT1   |  |  |  |

Figure 2 shows an example of a typical application with a separate supply voltage  $V_{\rm S}$  and using the transceiver with the IRED anode connected to the unregulated battery  $V_{\rm batt}$ . This method reduces the peak load of the regulated power supply and saves therefore costs. Alternatively all supplies can also be tied to only one voltage source. R1 and C1 are not used in this case and are depending on the circuit design in most cases not necessary.

In Fig. 2 an option is shown to operate the transmitter at two different power levels to switch for long range to low power mode for e.g. saving power for IrDA application but use the full range specification for remote control. The additional components are marked in the figure.

For operating at RS232 ports we recommend to use an encoder / decoder-module.



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#### $V_{batt} \approx 3 V$ C1 $V_{S} = 2.8 \text{ V}$ $V_{dd}$ IRED anode (1) IRED cathode (2) IRTX TXD (3) IRRX RXD (4) IR MODE SD (5) V<sub>CC1</sub> (6) C2 GND (8) 20038

Fig. 2 - Typical Application Circuit Grey: Optional for High/Low Switching

#### I/O AND SOFTWARE

In the description, already different I/Os are mentioned. Different combinations are tested and the function verified with the special drivers available from the I/O suppliers. In special cases refer to the I/O manual, the Vishay application notes, or contact directly Vishay Sales, Marketing or Application.

| TABLE 2 -      | TRUTH TAE    | BLE  |   |                |  |
|----------------|--------------|--|---|----------------|--|
|                | INF          | PUTS   | OUTP  | UTS            | REMARK   |
| SD             | TXD          | OPTICAL INPUT IRRADIANCE mW/m <sup>2</sup>                           | RXD   | TRANSMITTER    | OPERATION  |
| High<br>> 1 ms | x            | х  | Weakly pulled (500 k $\Omega$ ) to V <sub>CC1</sub> | 0              | Shutdown   |
|                | High < 50 µs | x  | Low active  | l <sub>e</sub> | Transmitting   |
|                | High > 50 µs | х  | High inactive                                       | 0              | Protection is active   |
| Low            | Low          | < 4  | High inactive                                       | 0              | Ignoring low signals below the IrDA defined threshold for noise immunity |
|                | Low          | > min. irradiance E <sub>e</sub><br>< max. irradiance E <sub>e</sub> | Low (active)  | 0              | Response to an IrDA compliant optical input signal                       |
|                | Low          | > max. irradiance E <sub>e</sub>                                     | Undefined   | 0              | Overload conditions can cause unexpected outputs                         |



#### **ASSEMBLY INSTRUCTIONS**

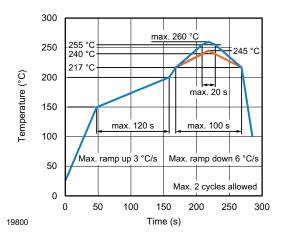
#### **Reflow Soldering**

- Reflow soldering must be done within 72 h while stored under a max. temperature of 30 °C, 60 % RH after opening the dry pack envelope
- Set the furnace temperatures for pre-heating and heating in accordance with the reflow temperature profile as shown in the diagram. Exercise extreme care to keep the maximum temperature below 260 °C. The temperature shown in the profile means the temperature at the device surface. Since there is a temperature difference between the component and the circuit board, it should be verified that the temperature of the device is accurately being measured
- Handling after reflow should be done only after the work surface has been cooled off

#### **Manual Soldering**

- Use a soldering iron of 25 W or less. Adjust the temperature of the soldering iron below 300 °C
- Finish soldering within 3 s
- Handle products only after the temperature has cooled off

#### **VISHAY LEAD (Pb)-FREE REFLOW SOLDER PROFILE**





#### **PACKAGE DIMENSIONS** in millimeters

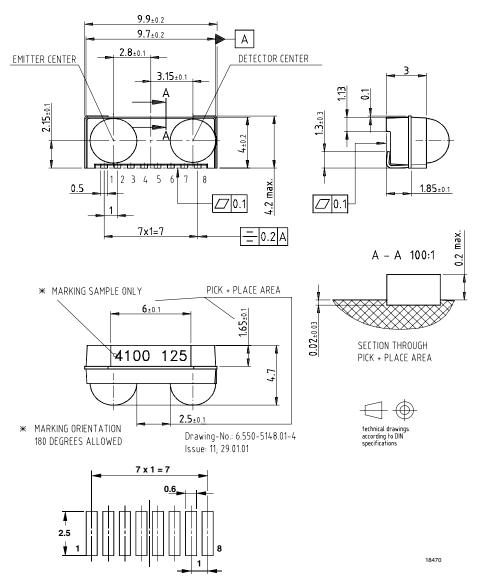


Fig. 3 - Package Drawing TFDU4101. Tolerance ± 0.2 mm if not otherwise mentioned

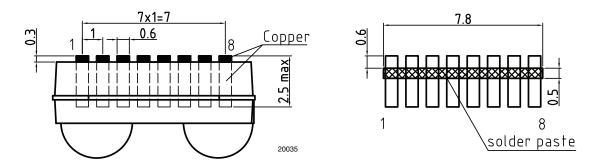


Fig. 4 - Recommended Footprint for Side View Applications and Solderpaste Mask



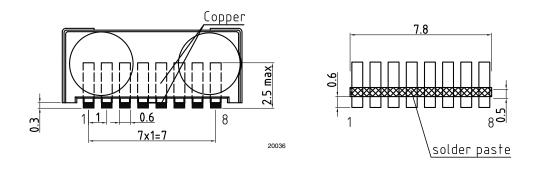


Fig. 5 - Recommended Footprint for Top View Applications and Solderpaste Mask

#### **TAPE DIMENSIONS FOR TT3** in millimeters

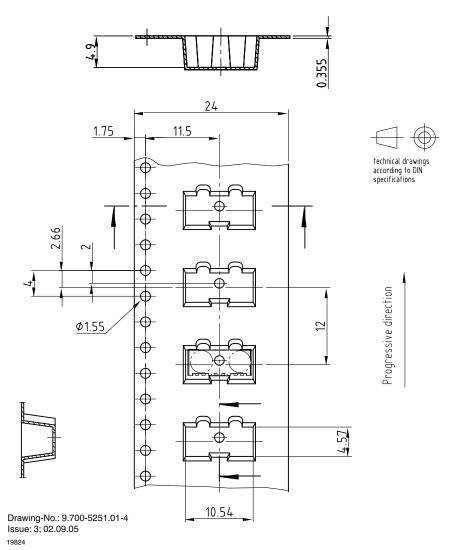


Fig. 6 - Tape Drawing, TFDU4101 for Top View Mounting, Tolerance  $\pm$  0.1 mm

#### **TAPE DIMENSIONS FOR TR3** in millimeters

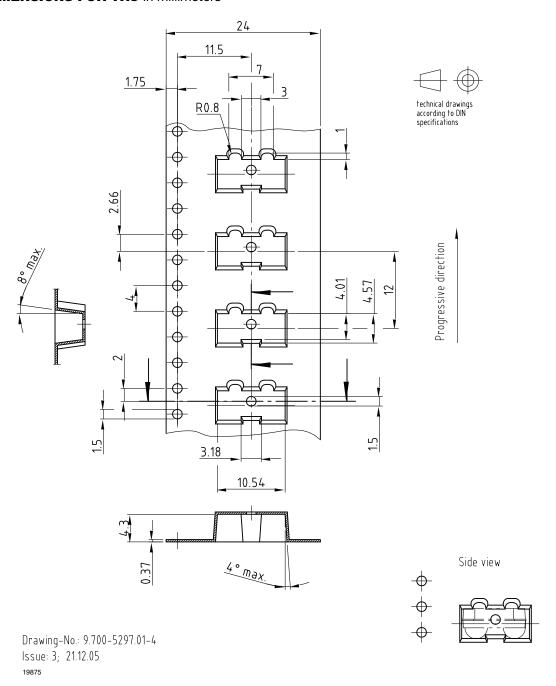
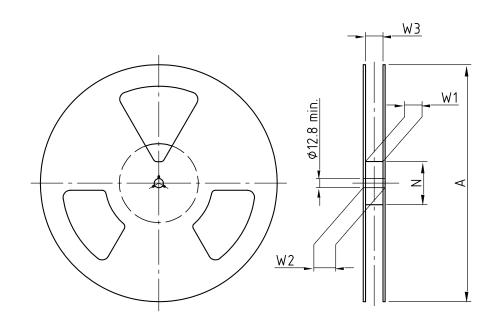


Fig. 7 - Tape Drawing, TFDU4101 for Side View Mounting, Tolerance  $\pm$  0.1 mm

#### **REEL DIMENSIONS** in millimeters



Reel hub 2:1

Drawing-No.: 9.800-5090.01-4

Issue: 1; 29.11.05

14017

Form of the leave open of the wheel is supplier specific.

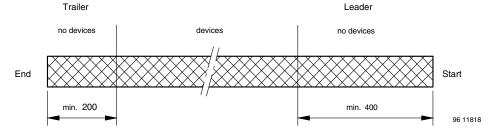
Dimension acc. to IEC EN 60 286-3



technical drawings according to DIN specifications

| TAPE WIDTH | A MAX. | N    | W <sub>1 MIN.</sub> | W <sub>2</sub> MAX. | W <sub>3</sub> MIN. | W <sub>3</sub> MAX. |
|------------|--------|------|---------------------|---------------------|---------------------|---------------------|
| (mm)       | (mm)   | (mm) | (mm)                | (mm)                | (mm)                | (mm)                |
| 24         | 330    | 60   | 24.4                | 30.4                | 23.9                |                     |

#### **LEADER AND TRAILER DIMENSIONS** in millimeters



#### **COVER TAPE PEEL STRENGTH**

According to DIN EN 60286-3 0.1 N to 1.3 N  $300 \pm 10$  mm/min.  $165^{\circ}$  to  $180^{\circ}$  peel angle

#### **LABEL**

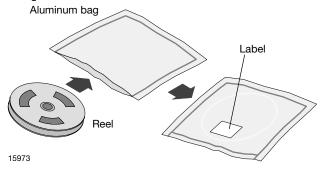
#### Standard bar code labels for finished goods

The standard bar code labels are product labels and used for identification of goods. The finished goods are packed in final packing area. The standard packing units are labeled with standard bar code labels before transported as finished goods to warehouses. The labels are on each packing unit and contain Vishay Semiconductor GmbH specific data.



#### **DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



#### FINAL PACKING

The sealed reel is packed into a cardboard box.

#### RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

# Vishay Semiconductors

After more than 72 h under these conditions moisture content will be too high for reflow soldering.

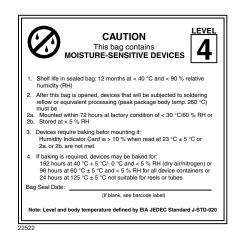
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C / - 0 °C and < 5 % RH (dry air / nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 125 °C + 5 °C not suitable for reel or tubes.

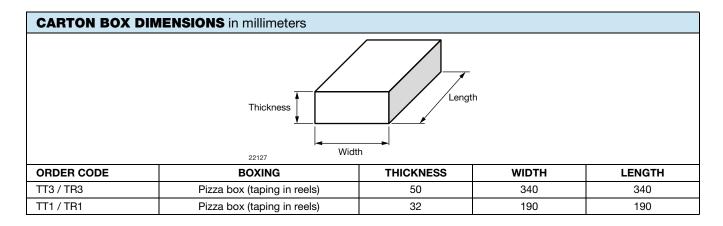
An EIA JEDEC® standard J-STD-020 level 4 label is included on all dry bags.



EIA JEDEC standard J-STD-020 level 4 label is included on all dry bags

#### **OUTER PACKAGING**

The sealed reel is packed into a pizza box.



| PLAIN WRITING         | ABBREVIATION | LENGTH       |  |
|-----------------------|--------------|--------------|--|
| Item-description      | -            | 18           |  |
| Item-number           | INO          | 8            |  |
| Selection-code        | SEL          | 3            |  |
| LOT-/serial-number    | BATCH        | 10           |  |
| Data-code             | COD          | 3 (YWW)      |  |
| Plant-code            | PTC          | 2            |  |
| Quantity              | QTY          | 8            |  |
| Accepted by           | ACC          | -            |  |
| Packed by             | PCK          | -            |  |
| Mixed code indicator  | MIXED CODE   | -            |  |
| Origin                | XXXXXX+      | Company logo |  |
| Long bar code top     | Туре         | Length       |  |
| Item-number           | N            | 8            |  |
| Plant-code            | N            | 2            |  |
| Sequence-number       | X            | 3            |  |
| Quantity              | N            | 8            |  |
| Total length          | -            | 21           |  |
| Short bar code bottom | Туре         | Length       |  |
| Selection-code        | X            | 3            |  |
| Data-code             | N            | 3            |  |
| Batch-number          | X            | 10           |  |
| Filter                | -            | 1            |  |
| Total length          | -            | 17           |  |

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

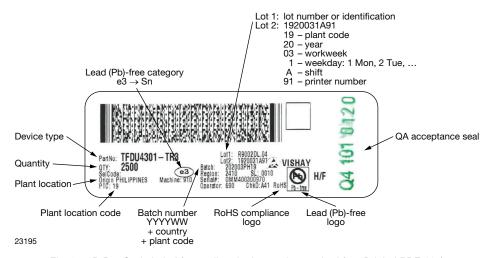


Fig. 8 - 2D Bar Code Label (according the bar code standard for 2D label PDF 417) for a Lead (Pb)-Free Device Made in Philippines, Detailed Description

#### **ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electrostatic sensitive devices warning labels are on the packaging.



# **Legal Disclaimer Notice**

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